NSN 5961-01-012-4886

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-012-4886
Inclosure Material:
Metal
Overall Length:
1.252 inches
Overall Height:
0.700 inches
Overall Width:
0.700 inches
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-66
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 repetitive peak off-state voltage
Current Rating Per Characteristic:
15.00 amperes forward current, total rms horsepower metric
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
1 case and 2 pin
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A110a0